

08/01/03
15915 U.S. PTO



Brouillette Kosie Prince

AGENTS

S. E. N. C.

PATENT AND TRADE MARK

July 31, 2003

22240 U.S. PTO
10/631825
08/01/03

**The Honorable Commissioner
of Patents and Trademarks**
P.O. Box 1450
Alexandria, VA 22313-1450
U.S.A.

Re : New US patent application claiming priority of Canadian patent
application no 2,398,166 filed August 14, 2002
Title : Method for modifying the impedance of semiconductor devices
using a focused heating source
Inventors : Alain LACOURSE; Hugues LANGLOIS; Yvon SAVARIA; Yves
GAGNON
Our file : 06042-006-US-02

Dear Madam/Sir:

The undersigned attorney has been authorized by the applicant to file the above-captioned patent application on their behalf.

The application is to be filed in accordance with the enclosed filing particulars.

Please use our deposit account number 02-3980 for the payment of the prescribed fees, i.e. US \$834.00

The Government filing fee is calculated as follows:

FOR	NO. FILED	NO. EXTRA	LARGE ENTITY	RATE	FEE
BASIC FEE					750
TOTAL CLAIMS	19				0
TOTAL INDEP CLAIMS	4 - (3)	1			84
MULTIPLE DEPENDENT CLAIM PRESENTED					0
TOTAL:					834

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Correspondence concerning the application should be addressed to:

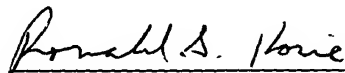
Ronald S. Kosie (Reg. No.: 28,814)
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If any other fees whatsoever are due, the US Patent Office is also hereby authorized to charge any such additional fees (or deposit any excess whatsoever) to our Deposit Account no. 02-3980.

All telephone conversations should be directed to Ronald S. Kosie or Robert Brouillette or Gaetan Prince at (514) 397-8500.

Respectfully submitted,

BROUILLETTE KOSIE PRINCE



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Encl.: Filing particulars
Specification pages 1 to 31
Claims page 32 to 39 including 19 claims
Abstract page 40
Drawings on 9 pages including Figure 1 to 9, 9a, 9b, 9c, and 10 to 17
Acknowledgment card

FILING PARTICULARS

Filing under 37 CFR 1.41(C)

TITLE: METHOD FOR MODIFYING THE IMPEDANCE OF
SEMICONDUCTOR DEVICES USING A FOCUSED
HEATING SOURCE

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APPLICANT: Same as the inventor

ENTITY STATUS: Large

PRIORITY: - Canadian Patent application no. 2,398,166
filed August 14, 2002

DOCUMENTS:

Enclosed:

- Specification pages 1 to 31
- Claims page 32 to 39 including 19 claims
- Abstract page 40
- Drawings on 9 pages including Figure 1 to 9, 9a, 9b, 9c, and 10 to 17
- Acknowledgment card

Brouillette Kosie Prince

To follow:

- Information disclosure statement form PTO/SB/08A
- Copy of prior art
- Combined Declaration and Power of Attorney
- Priority document

AGENTS:

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- Gaétan Prince Reg. No.: 33,107